PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive Type PDB-C138, with daylight filter Type PDB-C138F DETECTORS INC.



#### PACKAGE DIMENSIONS INCH [mm] -0.220 [5.60] Ø0.197 [5.00]-0.020 [0.51] SQ 2 PLACES ACTIVE AREA SURFACE 1.043 [26.5] 0.059 [1.50] MA ęI 400 P 0.100 [2.54] VIEWING 61 ANGLE CATHODE

0.984 [25.0]

0.038 [0.97]

#### **FEATURES**

High speed

Low cost

- Large active area
- **DESCRIPTION:** The **PDB-C138** detector is a 1.55 mm<sup>2</sup> planar pin photodiode packaged in a T 1 3/4, water clear plastic housing. Designed for high speed, low capacitance, photoconductive applications. The PDB-C138F includes a daylight filter.

-ANODE

CLEAR PLASTIC (PDB-C138)-BLACK PLASTIC (PDB-C138F)

0.070 [1.78] 0.059 [1.50] SQ ACTIVE AREA

ACTIVE AREA = 1.55 mm<sup>2</sup>

## **APPLICATIONS**

T 1 3/4 PLASTIC PACKAGE

Smoke detectors

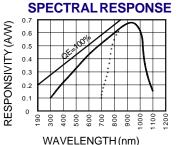
0.177 [4.50] CHIP POSITION

-0.342 [8.70]

- Light dimmers
- TV & VCR remotes

# ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

| SYMBOL           | MBOL PARAMETER              |     | MAX  | UNITS |  |
|------------------|-----------------------------|-----|------|-------|--|
| V <sub>BR</sub>  | Reverse Voltage             |     | 100  | V     |  |
| T <sub>stg</sub> | Storage Temperature         | -40 | +100 | °C    |  |
| T <sub>o</sub>   | Operating Temperature Range | -40 | +80  | °C    |  |
| T <sub>s</sub>   | Soldering Temperature*      |     | +260 | °C    |  |
| I <sub>L</sub>   | Light Current               |     | 0.5  | mA    |  |



\*1/16 inch from case for 3 secs max

## ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

| SYMBOL            | CHARACTERISTIC             | TESTCONDITIONS                | MIN | TYP                   | MAX  | UNITS   |
|-------------------|----------------------------|-------------------------------|-----|-----------------------|------|---------|
| I <sub>sc</sub>   | Short Circuit Current      | H = 100 fc, 2850 K            | 80  | 90                    |      | $\mu$ A |
| I <sub>D</sub>    | Dark Current               | H = 0, V <sub>R</sub> = 10 V  |     | 2                     | 30   | nA      |
| R <sub>SH</sub>   | Shunt Resistance           | H = 0, V <sub>R</sub> = 10 mV | .5  | 2                     |      | GΩ      |
| TCR <sub>SH</sub> | RSH Temp. Coefficient      | H = 0, V <sub>R</sub> = 10 mV |     | -8                    |      | %/°C    |
| C                 | Junction Capacitance       | H = 0, V <sub>R</sub> = 10 V* |     | 6                     | 10   | pF      |
| λrange            | Spectral Application Range | (without daylight filter)**   | 400 |                       | 1100 | nm      |
| λρ                | Spectral Response - Peak   |                               |     | 950                   |      | nm      |
| V <sub>BR</sub>   | Breakdown Voltage          | I = 10 μA                     | 50  | 100                   |      | V       |
| NEP               | Noise Equivalent Power     | V <sub>R</sub> = 10 V @ Peak  |     | 1.8x10 <sup>-13</sup> |      | W/ √ Hz |
| tr                | Response Time              | $RL = 1 K\Omega V_R = 50 V$   |     | 10                    |      | nS      |

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. \*f = 1 MHz, \*\* daylight filter= 700 - 1100 nm [FORM NO. 100-PDB-C138 REV A]